Double Lig	ht	
	1W High Power Infrared LED	
	Technical Data Sheet	
	Part No.: DL-HP10SIRA-1SIR120	

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Features:

- 1. High reliability.
- 2. High radiant intensity.
- 3. Low forward voltage.
- 4. Peak wavelength λp=850nm.
- 5. The product itself will remain within RoHS compliant version.

Descriptions:

- 1. The DL-HP10SIR Infrared Emitting Diode is a high intensity diode.
- 2. The device is spectrally matched with phototransistor, photodiode and infrared receiver module.

Applications:

- 1. Free air transmission system.
- 2. Optoelectronic switch.
- 3. Floppy disk drive.
- 4. Infrared applied system.
- 5. Smoke detector.

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Package Dimension: Ø8.00 [Ø0.315] Ø6.00 [Ø0.236] 50 [0,059] 1,10 [0,043] Anode(+) 1.35 [0.053] Cathode(-) Slug Cathode(-) — Anode(+) 0391 5,40 [0,213] Lens [0,203] 2.65 [0.104] 5.15 [0.012] 11.80 [0.465] 14.50 [0.571]

Part No.	Chip Material	Lens Color	Source Color
DL-HP10SIRA-1SIR120	GaAlAs	Water Clear	Infrared

Notes:

- 1. All dimensions are in millimeters.
- 2. Tolerance is ± 0.25 mm (.010") unless otherwise specified.
- 3. Specifications are subject to change without notice.

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♦ Absolute Maximum Ratings at Ta=25°C

Parameters	Symbol	Max.	Unit	
Power Dissipation	PD	1000	mW	
Peak Forward Current (1/10 Duty Cycle, 0.1ms Pulse Width)	IFP	1.00	А	
Forward Current	IF	350	mA	
Reverse Voltage	VR	5	V	
Operating Temperature Range	Topr	-10°C to +70°C		
Storage Temperature Range	Tstg	-20°C to +80°C		
Soldering Temperature	Tsld	260°C for 5 Seconds		

Electrical Optical Characteristics at Ta=25℃

Parameters	Symbol	Min.	Тур.	Max.	Unit	Test Condition
Radiant Intensity	le	110	180		mW/Sr	IF=350mA
Viewing Angle *	201/2		120		Deg	(Note 1)
Peak Emission Wavelength	λр		850		nm	IF=350mA
Spectral Bandwidth	Δλ		45		nm	IF=350mA
Forward Voltage	VF	1.30	1.50	1.80	V	IF=350mA
Reverse Current	IR			50	μΑ	V _R =5V

Notes:

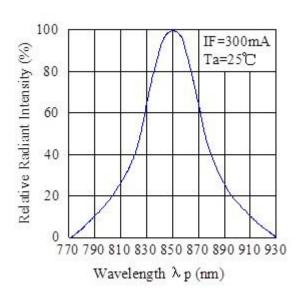
1. $\theta_{1/2}$ is the off-axis angle at which the luminous intensity is half the axial luminous intensity.

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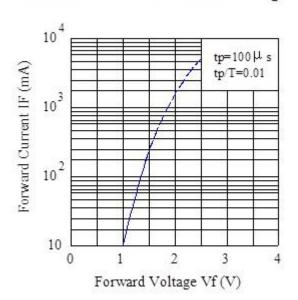
◆ Typical Electrical / Optical Characteristics Curves

(25°C Ambient Temperature Unless Otherwise Noted)

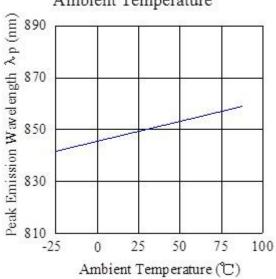
Spectral Distribution



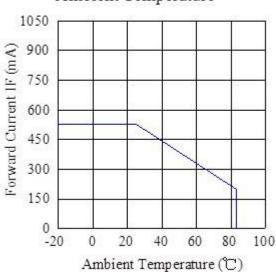
Forward Current & Forward Voltage



Peak Emission Wavelength & Ambient Temperature

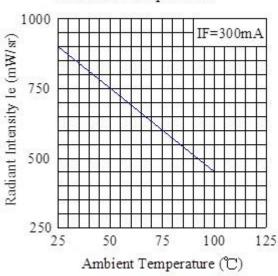


Forward Current & Ambient Temperature

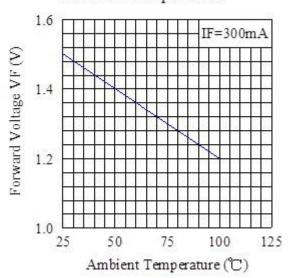


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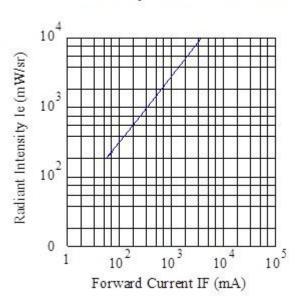
Relative Intensity & Ambient Temperature



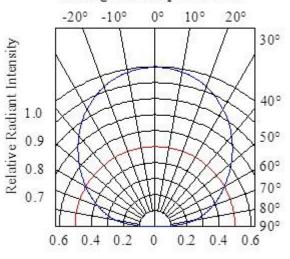
Forward Voltage & Ambient Temperature



Relative Intensity & Forward Current



Relative Radiant Intensity & Angular Displacement



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Reliability Test Items And Conditions:

The reliability of products shall be satisfied with items listed below:

Confidence level: 90%.

LTPD: 10%.

No.	ltem	Test Conditions	Test Hours/ Cycles	Sample Sizes	Failure Judgment Criteria	Ac/ Re
1	Reflow Soldering	TEMP.: 260℃±5℃ 5secs	6mins	22pcs		0/1
2	Temperature Cycle	H: $+100^{\circ}\mathbb{C}$ 15mins $ \int $ 5 mins $ \int $ L: $-40^{\circ}\mathbb{C}$ 15mins	50Cycles	22pcs	IR≧U*2 Ee≦L*0.8 VF≧U*1.2 U: Upper Specification	0/1
3	Thermal Shock	H: $+100^{\circ}\mathbb{C}$ 15mins $ \int 10mins $ L: $-10^{\circ}\mathbb{C}$ 5mins	50Cycles	22pcs		0/1
4	High Temperature Storage	TEMP.: +100°C	1000hrs	22pcs	Limit L: Lower	0/1
5	Lower Temperature Storage	TEMP.: -40°C	1000hrs	22pcs	Specification Limit	0/1
6	DC Operating Life	V _{CE} =5V	1000hrs	22pcs		0/1
7	High Temperature/ High Humidity	85℃ /85% R.H.	1000hrs	22pcs		0/1

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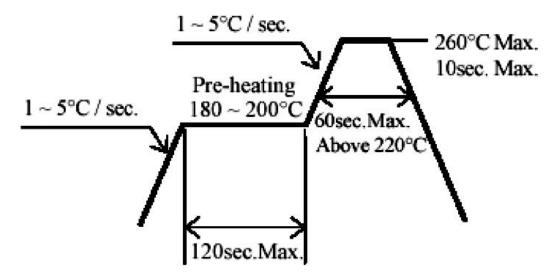
HONGKONG DOUBLE LIGHT ELECTRONICS TECHNOLOGY CO.,LIMITED

Please read the following notes before using the product:

1. Over-current-proof

Customer must apply resistors for protection, otherwise slight voltage shift will cause big current change (Burn out will happen).

- 2. Storage
 - 2.1 Do not open moisture proof bag before the products are ready to use.
 - 2.2 Before opening the package, the LEDs should be kept at 30℃ or less and 90%RH or less.
 - 2.3 The LEDs should be used within a year.
 - 2.4 After opening the package, the LEDs should be kept at 30℃ or less and 70%RH or less.
 - 2.5 The LEDs should be used within 168 hours (7 days) after opening the package.
 - 2.6 If the moisture adsorbent material (silica gel) has fabled away or the LEDs have exceeded the storage time, baking treatment should be performed using the following conditions. Baking treatment: $60\pm5^{\circ}$ C for 24 hours.
- 3. Soldering Condition
 - 3.1 Pb-free solder temperature profile.



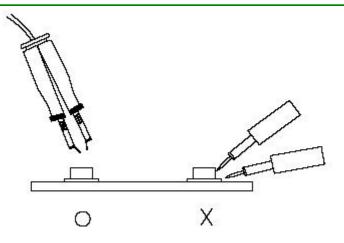
- 3.2 Reflow soldering should not be done more than two times.
- 3.3 When soldering, do not put stress on the LEDs during heating.
- 3.4 After soldering, do not warp the circuit board.
- 4. Soldering Iron

Each terminal is to go to the tip of soldering iron temperature less than 260° C for 5 seconds within once in less than the soldering iron capacity 25W. Leave two seconds and more intervals, and do soldering of each terminal. Be careful because the damage of the product is often started at the time of the hand solder.

5. Repairing

Repair should not be done after the LEDs have been soldered. When repairing is unavoidable, a double-head soldering iron should be used (as below figure). It should be confirmed beforehand whether the characteristics of the LEDs will or will not be damaged by repairing.

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6. Caution in ESD

Static Electricity and surge damages the LED. It is recommend to use a wrist band or anti-electrostatic glove when handling the LED. All devices, equipment and machinery must be properly grounded.

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